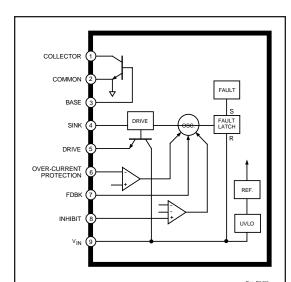
STR-S6707 THRU **STR-S6709**

OFF-LINE SWITCHING REGULATORS - WITH BIPOLAR SWITCHING TRANSISTOR



ABSOLUTE MAXIMUM RATINGS
Supply Voltage, V _{IN} 15 V
Output Voltage, V _{CEX}
Continuous Output Current, I _C See Table
1 ms Single-Pulse Output Current,
I _{CM} See Table
Sink Current, I _S See Table
Drive Current, I_D 700 mA
Feedback Current, I _{FDBK} 20 mA
Inhibit Voltage, V _{INH} 15 V
Over-Current Protection Voltage Range, V _{OCP} ±3.5 V
Insulation Voltage,V _{WM(RMS)} 2000 V
Package Power Diss., P _D See Graph
Output Junction Temperature, T _J +150°C
Internal Frame Temperature, T _F +125°C
Operating Temperature Range, T _A 20°C to +125°C
Storage Temperature Range, Teta40°C to +125°C
1 ala40 C IO +123 C

The STR-S6707, STR-S6708, and STR-S6709 are specifically designed to meet the requirement for increased integration and reliability in off-line quasi-resonant flyback converters. These devices incorporate the primary control and proportional drive circuit with a thirdgeneration high-voltage bipolar switching transistor.

Crucial system parameters such as maximum ON time and OFF time are fixed during manufacture. Local control circuit decoupling and layout are optimized within each device.

Cycle-by-cycle current limiting, under-voltage lock-out with hysteresis, over-voltage protection, and thermal shutdown protect these devices during all normal and overload conditions. Over-voltage protection and thermal shutdown are latched after a short delay. A versatile triple-level inhibit circuit includes the OFF time synchronization required to establish quasi-resonant operation. The inhibit function has also been expanded to initiate operation in stand-by mode in which the power supply delivers a small fraction of the steady-state output power. The dual requirements of dielectric isolation and low transient thermal impedance and steady-state thermal resistance are satisfied in an overmolded single-in-line power package.

Proven in substantial volumes, these devices and their fixedfrequency counterparts represent a significant advance in off-line SMPS reliability growth and integration.

FEATURES

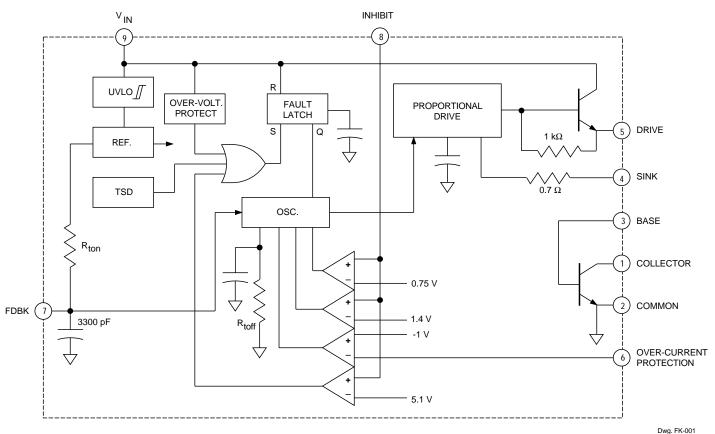
- Quasi-Resonant Operation for Low EMI and High Efficiency
- Output Power to 220 W
- Low-Power Output Standby Mode
- Pulse-by-Pulse Over-Current Protection
- Latched Over-Voltage and Thermal Protection
- Third-Generation Switching Transistor with Proportional Drive
- Maximum ON Time and Off Time Set During Manufacture
- Internal Under-Voltage Lockout with Hysteresis
- Over-Molded SIP with Integral Isolated Heat Spreader

Always order by complete part number:

Part Number	Max. Cont. Current, I _C	Peak Current, I _{CM}	Max. Sink Current, I _s
STR-S6707	6 A	12 A	1.5 A
STR-S6708	7.5 A	15 A	1.5 A
STR-S6709	10 A	20 A	2 A

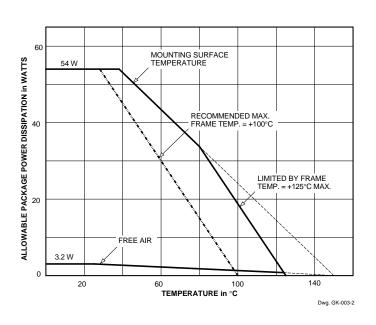


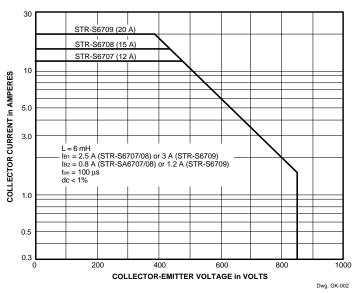
STR-S6707 AND STR-S6708 FUNCTIONAL BLOCK DIAGRAM



ALLOWABLE PACKAGE POWER DISSIPATION

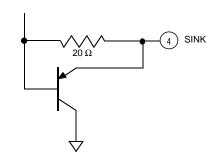
MAXIMUM SAFE OPERATING AREA







STR-S6709 FUNCTIONAL BLOCK DIAGRAM AS ABOVE EXCEPT FOR SINK OUTPUT

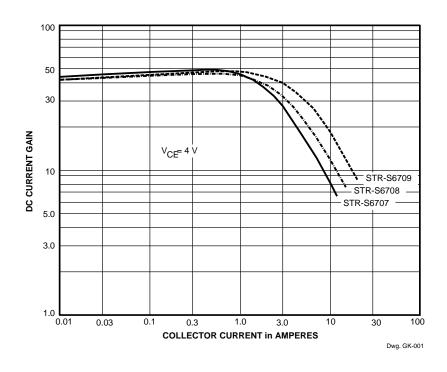


ELECTRICAL CHARACTERISTICS at T_A = +25°C, V_{IN} = 8.5 V, voltage measurements are referenced to Common (pin 2) (unless otherwise noted).

			Limits			
Characteristic	Symbol	Test Conditions	Min.	Тур.	Max.	Units
On-State Voltage	V _{INT}	Turn-on, increasing V _{IN}	7.6	8.0	8.4	V
Under-Voltage Lockout	V _{INQ}	Turn-off, decreasing V _{IN}	4.6	4.9	5.2	V
Over-Voltage Threshold	V _{OVP(th)}		9.2	_	10.7	V
Output Leakage Current	I _{CEX}	$V_{CE} = 850 \text{ V}, V_{BE} = -1.5 \text{ V}$	<u> </u>	_	100	μА
Output Saturation Voltage	V _{CE(sat)}	STR-S6707, $I_C = 2 \text{ A}$, $I_B = 400 \text{ mA}$	-	_	400	mV
		STR-S6708, I _C = 3 A, I _B = 600 mA	_	_	400	mV
		STR-S6709, I _C = 4 A, I _B = 800 mA	_	_	400	mV
	V _{BE(sat)}	STR-S6707, I _C = 2 A, I _B = 400 mA	_	_	1.5	V
		STR-S6708, I _C = 3 A, I _B = 600 mA	_	_	1.5	V
		STR-S6709, I _C = 4 A, I _B = 800 mA	_	_	1.5	V
DC Current Gain	h _{FE}	$V_{CE} = 4 \text{ V}, I_{C} = 1 \text{ A}$	29	_	61	_
Maximum ON Time	t _{on}		33	_	41	μs
Minimum OFF Time	t _{off}		45	_	55	μs
Over-Current Threshold	V _{OCP(th)}		-0.9	-1.0	-1.1	V
Feedback Threshold Volt.	V _{FDBK(th)}		_	650	_	mV
Inhibit Threshold Voltage	V _{INH(th)}	Oscillation stops	0.65	0.75	0.85	V
		Oscillation synchronized	_	1.4	2.0	V
		Oscillation stops (fault latch set)	3.2	5.1	5.6	V
Latch Holding Current	I _{INH}	V _{IN} reduced from 10.7 V to 4 V	_	_	500	μΑ
Latch Reset Voltage	V _Q	I _{IN} ≤ 100 μA, V _{IN} reduced from 10.7 V	2.5	3.1	_	V
Supply Current	I _{IN(ON)}	Operating	15	_	29	mA
	I _{IN(OFF)}		_	-	200	μΑ
Insulation RMS Voltage	V _{WM(RMS)}	All terminals simultaneous reference metal plate against backside	2000	_	-	V
Thermal Shutdown	T _J		125	150	_	°C
Thermal Resistance	$R_{\theta JM}$	Output junction to mounting surface	_	2.0	-	°C/W

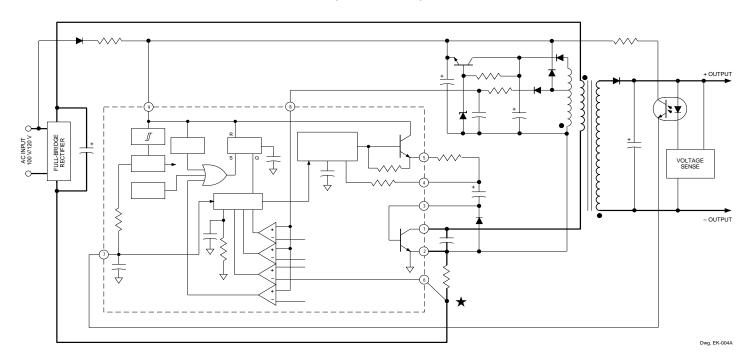
NOTES: Negative current is defined as coming out of (sourcing) the specified device terminal. Typical Data is for design information only.

TYPICAL CHARACTERISTICS



TYPICAL QUASI-RESONANT FLYBACK CONVERTER

WARNING: lethal potentials are present. See text.



APPLICATIONS INFORMATION

WARNING — These devices are designed to be operated at lethal voltages and energy levels. Circuit designs that embody these components must conform with applicable safety requirements. Precautions must be taken to prevent accidental contact with power-line potentials. Do not connect grounded test equipment.

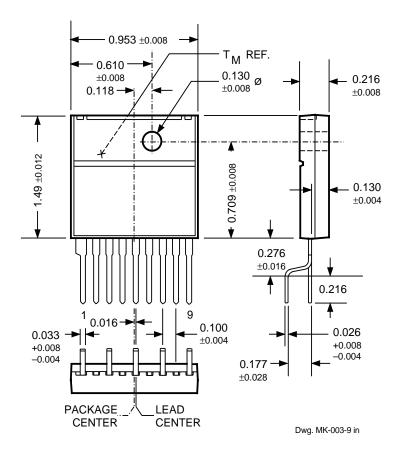
The use of an isolation transformer is recommended during circuit development and breadboarding.

Recommended mounting hardware torque:

4.34 – 5.79 lbf•ft (6 – 8 kg•cm or 0.588 – 0.784 Nm).

Recommended metal-oxide-filled, alkyl-degenerated oil base, silicone grease: Dow Corning 340, or equivalent

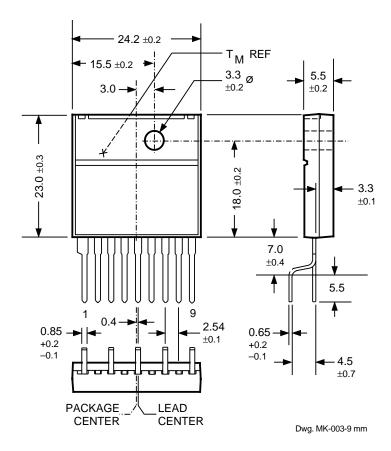
Dimensions in Inches (Based on 1 mm = 0.03937")



NOTE: Exact body and lead configuration at vendor's option within limits shown.



Dimensions in Millimeters



POWER CONVERSION/POWER MANAGEMENT

SWITCHING REGULATOR PMCMs

Part							
Number*	Application	AC In	Max Po	Power Switch			
5703	Quasi-Resonant Flyback Converter	110/120 V	140 W	500 V	6 A	Bipolar	
5707	Quasi-Resonant Flyback Convertter	85-265 V	90 W	850 V	6 A	Bipolar	
		220/240V	140 W				
5708	Quasi-Resonant Flyback Converter	85-265 V	120 W	850 V	7.5 A	Bipolar	
		220/240 V	180 W				
6511	Quasi-Resonant Flyback Converter	110/120 V	180 W	450 V	11 A	MOSFET	
6525	Quasi-Resonant Flyback Converter	85-265 V	120 W	600 V	6 A	MOSFET	
6529	Quasi-Resonant Flyback Converter	220/240 V	180 W	800 V	5.4 A	MOSFET	
6703	Quasi-Resonant Flyback Converter	110/120V	140 W	500 V	6 A	Bipolar	
6704	Quasi-Resonant Flyback Converter	110/120 V	100 W	500 V	5 A	Bipolar	
6707	Quasi-Resonant Flyback converter	85-265 V	90 W	850 V	6 A	Bipolar	
		220/240 V	140 W				
6708	Quasi-Resonant Flyback Converter	85-265 V	120 W	850 V	7.5 A	Bipolar	
		220/240 V	180 W				
6709	Quasi-Resonant Flyback Converter	85-265 V	160 W	850 W	10 A	Bipolar	
		220/240 V	220 W			•	

^{*} Complete part number includes additional characters to indicate operating temperature range and package style.

LINEAR REGULATOR ICs

Part					
Number*	Vo	Max DC In	Max Dropout	Max I _O	Package
8181	5.0 V	10 V	300 mV @ 500 mA	1.0 A	16-lead SOIC
8183	3.0 V	10 V	300 mV @ 125 mA	250 mA	6-lead SOT-89
8184	3.0 V	10 V	300 mV @ 125 mA	250 mA	SOT-89
8186	3.3 V	10 V	300 mV @ 125 mA	250 mA	6-lead SOT-89
8187	3.3 V	10 V	300 mV @ 125 mA	250 mA	SOT-89

^{*} Complete part number includes additional characters to indicate operating temperature range and package style.

Also — 83145 and 84145 Latched, Universal Input-Voltage Switches.

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